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# 8-Input Universal Shift/ **Storage Register with Common Parallel I/O Pins**

The MC74AC299/74ACT299 is an 8-bit universal shift/storage register with 3-state outputs. Four modes of operation are possible: hold (store), shift left, shift right and load data. The parallel load inputs and flip-flop outputs are multiplexed to reduce the total number of package pins. Additional outputs are provided for flip-flops Q<sub>0</sub>, Q<sub>7</sub> to allow easy serial cascading. A separate active LOW Master Reset is used to reset the register.

- Common Parallel I/O for Reduced Pin Count
- Additional Serial Inputs and Outputs for Expansion
- Four Operating Modes: Shift Left, Shift Right, Load and Store
- 3-State Outputs for Bus-Oriented Applications
- Outputs Source/Sink 24 mA
- 'ACT299 Has TTL Compatible Inputs
- These devices are available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative

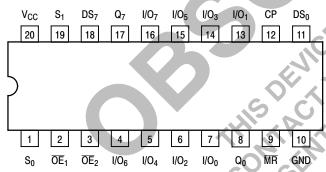


Figure 1. Pinout: 20-Lead Packages Conductors (Top View)

#### **PIN ASSIGNMENT**

PIN	FUNCTION
CP	Clock Pulse Input
DS <sub>0</sub>	Serial Data Input for Right Shift
DS <sub>7</sub>	Serial Data Input for Left Shift
S <sub>0</sub> , S <sub>1</sub>	Mode Select Inputs
MR	Asynchronous Master Reset
$\overline{OE}_1$ , $\overline{OE}_2$	3-State Output Enable Inputs
I/O <sub>0</sub> -I/O <sub>7</sub>	Parallel Data Inputs or 3-State Parallel Outputs
Q <sub>0</sub> , Q <sub>7</sub>	Serial Outputs



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PDIP-20 **N SUFFIX CASE 738** 



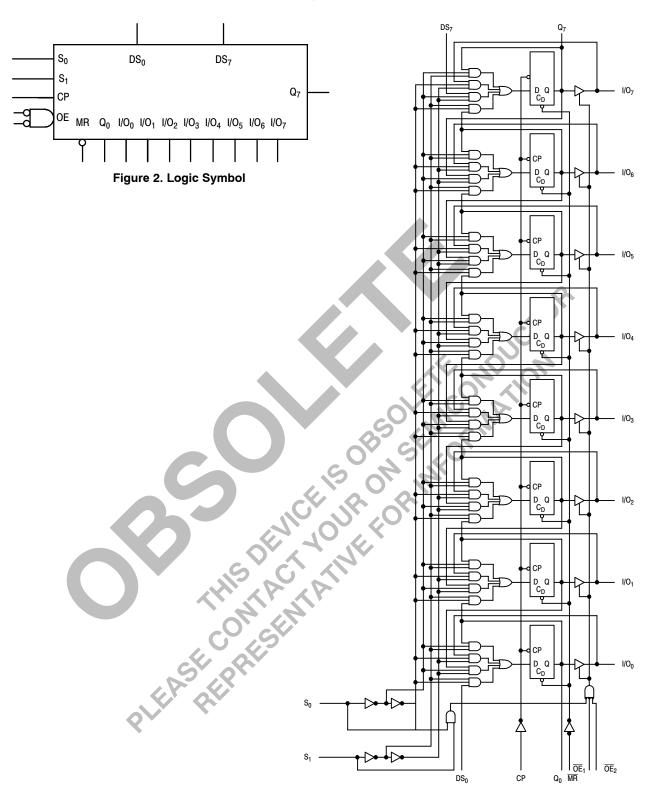
SO-20 **DW SUFFIX CASE 751** 

# ORDERING INFORMATION

Device	Package	Shipping
MC74AC299N	PDIP-20	18 Units/Rail
MC74ACT299N	PDIP-20	18 Units/Rail
MC74AC299DW	SOIC-20	38 Units/Rail
MC74AC299DWR2	SOIC-20	1000 Tape & Reel
MC74ACT299DW	SOIC-20	38 Units/Rail
MC74ACT299DWR2	SOIC-20	1000 Tape & Reel

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 9 of this data sheet.



NOTE: That this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

#### **FUNCTIONAL DESCRIPTION**

The MC74AC299/74ACT299 contains eight edge–triggered D–type flip–flops and the interstage logic necessary to perform synchronous shift left, shift right, parallel load and hold operations. The type of operation is determined by  $S_0$  and  $S_1$ , as shown in the Truth Table. All flip–flop outputs are brought out through 3–state buffers to separate I/O pins that also serve as data inputs in the parallel load mode.  $Q_0$  and  $Q_7$  are also brought out on other pins for expansion in serial shifting of longer words.

A LOW signal on  $\overline{MR}$  overrides the Select and CP inputs and resets the flip-flops. All other state changes are initiated by the rising edge of the clock. Inputs can change when the clock is in either state provided only that the recommended setup and hold times, relative to the rising edge of CP, are observed.

A HIGH signal on either  $\overline{OE}_1$  or  $\overline{OE}_2$  disables the 3\_state buffers and puts the I/O pins in the high impedance state. In this condition the shift, hold, load and reset operations can still occur. The 3–state buffers are also disabled by HIGH signals on both  $S_0$  and  $S_1$  in preparation for a parallel load operation.

#### **TRUTH TABLE**

	Inp	uts		Pagnamag
MR	S <sub>1</sub>	S <sub>0</sub>	СР	Response
L	Χ	Χ	Х	Asynchronous Reset; Q <sub>0</sub> –Q <sub>7</sub> = LOW
Н	Н	Н	」	Parallel Load; I/O <sub>n</sub> → Q <sub>n</sub>
Н	L	Н		Shift Rights; $DS_0 \rightarrow Q_0$ , $Q_0 \rightarrow Q_1$ , etc.
Н	Н	L	Г	Shift Left; $DS_7 \rightarrow Q_7$ , $Q_7 \rightarrow Q_6$ , etc.
Н	L⊸	L	Х	Hold

H = HIGH Voltage Level

#### **MAXIMUM RATINGS\***

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA
l <sub>OUT</sub>	DC Output Sink/Source Current, per Pin	±50	mA
I <sub>CC</sub>	DC V <sub>CC</sub> or GND Current per Output Pin	±50	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

<sup>\*</sup>Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit
V	Complex Velters	'AC	2.0	5.0	6.0	V
V <sub>CC</sub>	Supply Voltage	'ACT	4.5	5.0	5.5	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	ı	V <sub>CC</sub>	V
	, D (X	V <sub>CC</sub> @ 3.0 V	-	150	-	
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	-	ns/V
	Q	V <sub>CC</sub> @ 5.5 V	-	25	-	
+ +.	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	-	10	-	ns/V
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	-	8.0	-	115/ V
TJ	Junction Temperature (PDIP)		-	-	140	°C
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C
I <sub>OH</sub>	Output Current – High		-	-	-24	mA
I <sub>OL</sub>	Output Current – Low		-	-	24	mA

<sup>1.</sup> V<sub>IN</sub> from 30% to 70% V<sub>CC</sub>; see individual Data Sheets for devices that differ from the typical input rise and fall times.

L = LOW Voltage Level

X = Immaterial

 $<sup>\</sup>Gamma$  = LOW-to-HIGH Transition

<sup>2.</sup> V<sub>IN</sub> from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

## **DC CHARACTERISTICS**

			74	AC	74AC		
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = ·	+25°C	T <sub>A</sub> = -40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	٧	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	<b>V</b>	$V_{IN} = V_{IL}$ or $V_{IH}$ -12 mA $I_{OH}$ -24 mA -24 mA
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	MD	Ι <sub>ΟUT</sub> = 50 μΑ
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44		$^{*}V_{IN} = V_{IL} \text{ or } V_{IH}$ $12 \text{ mA}$ $I_{OL} \qquad 24 \text{ mA}$ $24 \text{ mA}$
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	S	±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND
I <sub>OZT</sub>	Maximum 3–State Current	5.5		±0.6	±6.0	μΑ	$\begin{aligned} &V_{I}\left(OE\right) = V_{IL},  V_{IH} \\ &V_{I} = V_{CC},  GND \\ &V_{O} = V_{CC},  GND \end{aligned}$
I <sub>OLD</sub>	†Minimum Dynamic	5.5	10	(- <u>-</u>	75	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5		_	-75	mA	V <sub>OHD</sub> = 3.85 V Min
Icc	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND

<sup>\*</sup>All outputs loaded; thresholds on input associated with output under test.

# AC CHARACTERISTICS (For Figures and Waveforms - See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

				74AC		74AC			
Symbol	Parameter	V <sub>CC</sub> * (V)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
f <sub>max</sub>	Maximum Input Frequency	3.3 5.0	90 130	-	1 1	80 105	1 1	MHz	3–3
t <sub>PLH</sub>	Propagation Delay CP to Q <sub>0 or</sub> Q <sub>7</sub>	3.3 5.0	8.5 5.5	-	20.5 14	7.0 4.5	22 15	ns	3–6
t <sub>PHL</sub>	Propagation Delay CP to Q <sub>0 or</sub> Q <sub>7</sub>	3.3 5.0	8.5 5.5	1 1	21.5 14.5	7.0 5.0	23 16	ns	3–6

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

<sup>†</sup>Maximum test duration 2.0 ms, one output loaded at a time.

NOTE:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

		V <sub>CC</sub> *		74AC		74.	AC		
Symbol	Parameter		T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay CP to I/O <sub>n</sub>	3.3 5.0	9.0 6.0	- -	20.5 14.5	7.5 5.0	22.5 16	ns	3–6
t <sub>PHL</sub>	Propagation Delay CP to I/O <sub>n</sub>	3.3 5.0	10 6.5	-	23 16	8.5 6.0	24.5 17.5	ns	3–6
t <sub>PHL</sub>	Propagation Delay $\overline{\rm MR}$ to ${\rm Q_0}$ or ${\rm Q_7}$	3.3 5.0	9.0 5.5	-	22.5 15.5	7.5 5.0	25.0 17.0	ns	3–6
t <sub>PHL</sub>	Propagation Delay MR to I/On	3.3 5.0	9.0 5.5	-	21.5 15.0	7.5 5.0	24.0 16.5	ns	3–6
t <sub>PZH</sub>	Output Enable Time  OE to I/On	3.3 5.0	7.0 4.5	1	18 12.5	6.0 4.0	19.5 13.5	ns	3–7
t <sub>PZL</sub>	Output Enable Time  OE to I/On	3.3 5.0	7.0 5.0	1	18 12.5	6.0 4.0	20.5 14	ns	3–8
t <sub>PHZ</sub>	Output Disable Time  OE to I/On	3.3 5.0	6.5 3.5	-	18.5 14	5.5 3.0	19.5 15	ns	3–7
t <sub>PLZ</sub>	Output Disable Time  OE to I/On	3.3 5.0	5.5 3.5	-//	17 12.5	4.5 2.0	19 13.5	ns	3–8

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

## **AC OPERATING REQUIREMENTS**

PLZ	OE to I/O <sub>n</sub>	5.0	3.5	- 12.5	2.0 13.5		
Voltage Ra	nge 3.3 V is 3.3 V ±0.3 V. nge 5.0 V is 5.0 V ±0.5 V.		BS	OF MIC	MA		
110 01 211		Co	) 2	74AC	74AC		
Symbol	Parameter	V <sub>cc</sub> * (V)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF		Fig. No.
		O	Тур	Guaranteed	d Minimum		
t <sub>s</sub>	Setup Time, HIGH or LOW S <sub>0</sub> or S <sub>1</sub> to CP	3.3 5.0	- -	8.0 5.0	8.5 5.5	ns	3–9
t <sub>h</sub>	Hold Time, HIGH or LOW S <sub>0</sub> or S <sub>1</sub> to CP	3.3 5.0	- -	0.5 1.0	0.5 1.0	ns	3–9
t <sub>s</sub>	Setup Time, HIGH or LOW I/On to CP	3.3 5.0		5.5 3.5	6.0 4.0	ns	3–9
t <sub>h</sub>	Hold Time, HIGH or LOW I/On to CP	3.3 5.0		0 1.0	0 1.0	ns	3–9
t <sub>s</sub>	Setup Time, HIGH or LOW DS <sub>0</sub> or DS <sub>7</sub> to CP	3.3 5.0	-	6.5 4.0	7.0 4.5	ns	3–6
t <sub>h</sub>	Hold Time, HIGH or LOW DS <sub>0</sub> or DS <sub>7</sub> to CP	3.3 5.0	- -	0 1.0	0.5 1.0	ns	3–6
t <sub>w</sub>	CP Pulse Width, LOW	3.3 5.0	- -	4.5 3.5	5.0 3.5	ns	3–6
t <sub>w</sub>	MR Pulse Width, LOW	3.3 5.0	- -	4.5 3.5	5.0 3.5	ns	3–9
t <sub>rec</sub>	Recovery Time MR to CP	3.3 5.0	- -	1.5 1.5	1.5 1.5	ns	3–9

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

## **DC CHARACTERISTICS**

			744	CT	74ACT		
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		4.5 5.5	- -	3.86 4.86	3.76 4.76	V	$^*V_{IN} = V_{IL} \text{ or } V_{IH}$ $-24 \text{ mA}$ $I_{OH}$ $-24 \text{ mA}$
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		4.5 5.5	-	0.36 0.36	0.44 0.44	٧	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ $24 \text{ mA}$ $I_{OL}$ $24 \text{ mA}$
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	Ā	±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND
I <sub>OZT</sub>	Maximum 3-State Current	5.5	_	±0.6	±6.0	μΑ	$\begin{aligned} &V_{I}\left(OE\right) = V_{IL},  V_{IH} \\ &V_{I} = V_{CC},  GND \\ &V_{O} = V_{CC},  GND \end{aligned}$
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	OY,	1.5	mA	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V
I <sub>OLD</sub>	†Minimum Dynamic	5.5	5	0	75	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5	() - <u> </u>	2-	-75	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	0)	8.0	80	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND

<sup>\*</sup>All outputs loaded; thresholds on input associated with output under test.
†Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms - See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

	Parameter			74ACT		74	CT			
Symbol		V <sub>CC</sub> * (V)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			T <sub>A</sub> = - to +8 C <sub>L</sub> = 8		Unit	Fig. No.	
			Min	Тур	Max	Min	Max			
f <sub>max</sub>	Maximum Input Frequency	5.0	120	-	-	110	-	MHz	3–3	
t <sub>PLH</sub>	Propagation Delay CP to $Q_0$ or $Q_7$	5.0	4.0	-	12.5	3.0	14	ns	3–6	
t <sub>PHL</sub>	Propagation Delay CP to $Q_0$ or $Q_7$	5.0	4.0	-	13.5	3.5	15	ns	3–6	
t <sub>PLH</sub>	Propagation Delay CP to I/O <sub>n</sub>	5.0	4.5	-	12.5	4.5	13.5	ns	3–6	
t <sub>PHL</sub>	Propagation Delay CP to I/O <sub>n</sub>	5.0	5.0	1	15	4.5	16.5	ns	3–6	
t <sub>PHL</sub>	Propagation Delay MR to Q <sub>0 or</sub> Q <sub>7</sub>	5.0	4.0	-	15	4.0	18	ns	3–6	
t <sub>PHL</sub>	Propagation Delay MR to I/On	5.0	4.0	-	14.5	3.5	17.5	ns	3–6	
t <sub>PZH</sub>	Output Enable Time OE to I/On	5.0	2.5	-	12	1.5	13	ns	3–7	
t <sub>PZL</sub>	Output Enable Time	5.0	2.0	1-1	12	1.5	13.5	ns	3–8	
t <sub>PHZ</sub>	Output Disable Time OE to I/On	5.0	2.0		12.5	2.0	13.5	ns	3–7	
t <sub>PLZ</sub>	Output Disable Time  OE to I/On	5.0	2.5	7 - 3	11.5	2.0	12.5	ns	3–8	
*Voltage Ran	Output Disable Time OE to I/On  Output Disable Time OE to I/On  Output Disable Time OE to I/On  nge 5.0 V is 5.0 V ±0.5 V.	CIN		5R.						

<sup>\*</sup>Voltage Range 5.0 V is 5.0 V ±0.5 V.

## **AC OPERATING REQUIREMENTS**

	Parameter			74ACT	74ACT		
Symbol				<sub>A</sub> = +25°C <sub>L</sub> = 50 pF	T <sub>A</sub> = -40°C to +85°C C <sub>L</sub> = 50 pF	Unit	Fig. No.
			Тур	Guaranteed	d Minimum		
t <sub>s</sub>	Setup Time, HIGH or LOW S <sub>0</sub> or S <sub>1</sub> to CP	5.0	-	5.0	5.5	ns	3–9
t <sub>h</sub>	Hold Time, HIGH or LOW S <sub>0</sub> or S <sub>1</sub> to CP	5.0	ı	1.0	1.0	ns	3–9
t <sub>s</sub>	Setup Time, HIGH or LOW I/On to CP	5.0	ı	4.0	4.5	ns	3–9
t <sub>h</sub>	Hold Time, HIGH or LOW I/O <sub>n</sub> to CP	5.0	-	1.0	1.0	ns	3–9
t <sub>s</sub>	Setup Time, HIGH or LOW $\mathrm{DS}_0$ or $\mathrm{DS}_7$ to $\mathrm{CP}$	5.0		4.5	5.0	ns	3–6
t <sub>h</sub>	Hold Time, HIGH or LOW $\mathrm{DS}_0$ or $\mathrm{DS}_7$ to $\mathrm{CP}$	5.0	-	1.0	1.0	ns	3–6
t <sub>w</sub>	CP Pulse Width HIGH or LOW	5.0		4.0	4.5	ns	3–9
t <sub>w</sub>	MR Pulse Width, LOW	5.0	-	3.5	3.5	ns	3–9
t <sub>rec</sub>	Recovery Time MR to CP	5.0	-	1.5	1.5	ns	3–9

<sup>\*</sup>Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

# **CAPACITANCE**

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	170	pF	V <sub>CC</sub> = 5.0 V

#### **MARKING DIAGRAMS**

PDIP-20

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SO-20 

AC299 **AWLYYWW** 

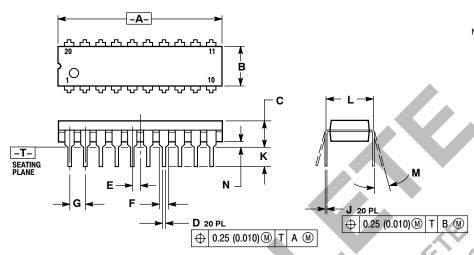
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ACT299 AWLYYWW 

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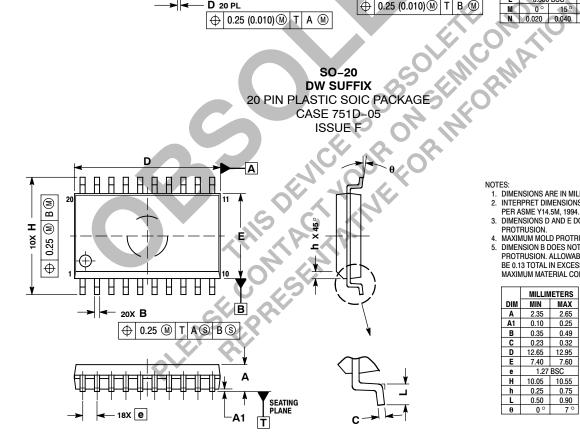
## PACKAGE DIMENSIONS

## PDIP-20 **N SUFFIX** 20 PIN PLASTIC DIP PACKAGE CASE 738-03 **ISSUE E**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	1.010	1.070	25.66	27.17
В	0.240	0.260	6.10	6.60
С	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
Е	0.050 BSC		1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100 BSC		2.54 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62 BSC	
M	°	15°	0°	15°
N	0.020	0.040	0.51	1.01



- AUTES:

  1. DIMENSIONS ARE IN MILLIMETERS.
  2. INTERPRET DIMENSIONS AND TOLERANCES
  PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.

  4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10	0.25		
В	0.35	0.49		
c	0.23	0.32		
ם	12.65	12.95		
Е	7.40	7.60		
е	1.27 BSC			
Н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
θ	0 °	7 °		



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